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				Application Number	Not Yet Assigned 10/699652
				Filing Date	Concurrently Herewith
				First Named Inventor	Hagop A. Nazarian
				Art Unit	2827 2827
				Examiner Name	Not Yet Assigned T.T. Nguyen
Sheet	1	of	1	Attorney Docket Number	M4065.0901/P901

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NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
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